



Product datasheet

#### **Description**

The HTL7G06S009P is an unmatched discrete LDMOS Power Amplifier with 8W saturated output power covering frequency range for VHF/UHF applications.

#### **Features**

Operating Frequency Range: VHF/UHF

Operating Drain Voltage: +3.6V/+7.2V

Saturation Output Power: 8W

Enhanced robustness design without device degradation

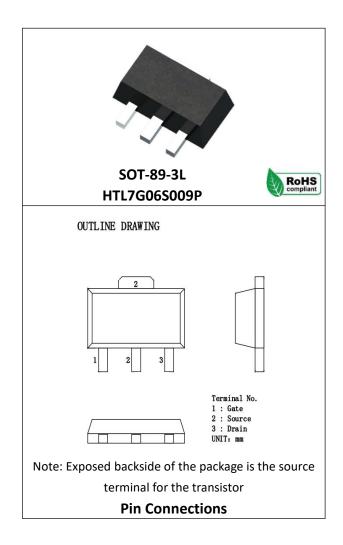
Internally integrated enhanced ESD design

Freq	Vdd	Pin	Pout	Eff
(MHz)	(V)	(W)	(W)	(%)
400-470	3.6	0.10	2.3	60
400-470	7.2	0.32	8.0	60
136-174	7.2	0.32	8.5	60

Test conditions unless otherwise noted: 25 °C test on HOTLO Application Board

#### **Applications**

- VHF Band handheld Walkie-talkie
- UHF Band handheld Walkie-talkie
- 1.8-1000MHz other application Drivers or Final stage Amplifiers



#### **Ordering Information**

Part Number	Description
HTL7G06S009P	Reel Package
HTL7G06S009P EVB	136 - 174 MHz EVB
HTL7G06S009P EVB1	400 - 470 MHz EVB



Product datasheet

#### **Absolute Maximum Ratings**

Parameter	Range/Value	Unit
Drain voltage (VDSS)	-0.5 to +25	V
Gate voltage (V <sub>GS</sub> )	-5 to +10	V
Operation voltage (VDD)	+9.0	V
Storage Temperature (Tstg)	-55 to +150	°C
Junction Temperature (T <sub>J</sub> )	-40 to +150	°C
Thermal Resistance Junction to Case (Rтн)	6.5	°C /W

## **Electrical Specification**

#### **DC Characteristics**

Parameter	Conditions	Min	Тур	Max	Unit
Breakdown Voltage V(BR)DSS	Vgs=0V, Ids=39.6uA	25	-	-	V
Gate-Source Threshold	Vds=Vgs, Ids=39.6uA	1.2	1.5	1.8	V
Voltage V <sub>GS(th)</sub>	vus-vgs, ius-39.0uA	1.2	1.5	1.0	V
Drain Leakage Current loss	Vgs=0V, Vds=12V	-	-	1	uA
Gate Leakage Current Igss	Vgs=10V, Vds=0V	-	-	1	uA

#### **Load Mismatch Test**

Condition	Test Result
VSWR=20:1, at all Phase Angles, $V_{DD}$ = +8.4Vdc, $I_{DQ}$ = 200mA,	No Device
CW signal 38.5 dBm @435MHz test on HOTLO Application Board	Degradation

#### **RF Characteristics (CW)**

Freq (MHz)	Vdd (V)@Idq (mA)	Pin (W)	Pout (W)	Eff (%)
174	7.2@200	0.32	8.8	65
435	7.2@200	0.32	8.6	65

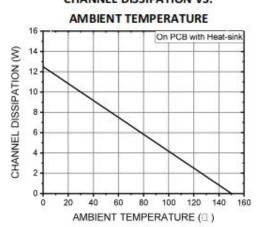
Test conditions unless otherwise noted: 25 °C test on HOTLO Application Board

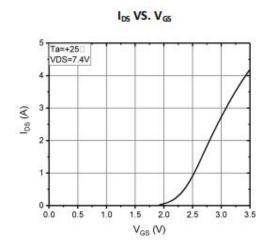


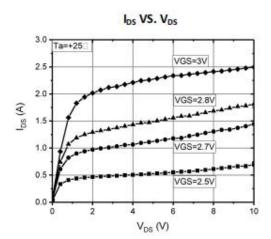
Product datasheet

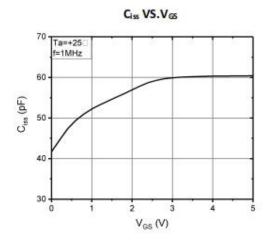
#### **DC Performance**

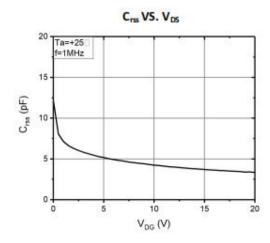
#### CHANNEL DISSIPATION VS.

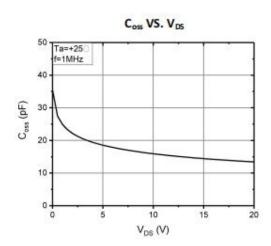












Test conditions unless otherwise noted: 25 °C

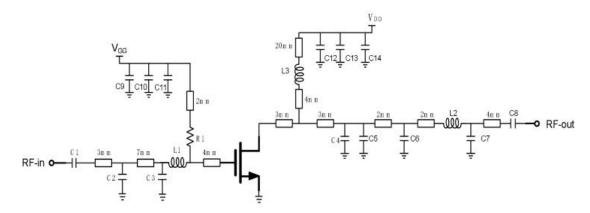
#### HTL7G06S009P



## 8W, 1.8 - 1000 MHz LDMOS Amplifier

Product datasheet

## HTL7G06S009P 400 - 470 MHz Reference Design, 3.6V@200mA



**EVB Layout** 

#### BoM - HTL7G06S009P 400 - 470 MHz Reference Design, 3.6V@200mA

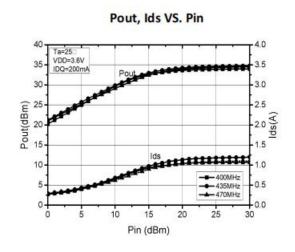
Reference	Value	Description	Manufacturer	P/N
Q1	-	8W, 1.8 - 1000 MHz LDMOS PA	Holto	HTL7G06S009P
C1, C8, C11, C14	100pF	MLCC	Murata	GRM1885C1H101JA01
C2	15pF	MLCC	Murata	GRM1885C1H150JA01
С3	12pF	MLCC	Murata	GRM1885C1H120JA01
C4, C6	20pF	MLCC	Murata	GRM1885C1H200JA01
C5	6pF	MLCC	Murata	GRM1885C1H6R0JA01
C7	7pF	MLCC	Murata	GRM1885C1H7R0JA01
С9	4.7uF	MLCC	Murata	GRM32ER61H474KA12L
C10, C13	1nF	MLCC	Murata	GRM1885C1H102JA01
C12	10uF	MLCC	Murata	GRM32ER61H105KA12L
L1		2.7nH/0603	Murata	GRM1885C1H272JA01
L2	D: 0.31 mm, Inside: 1.2 mm, 4 Turns		-	Enameled wire
L3	D: 0.35 mm, Inside: 1.5 mm, 8 Turns		-	Enameled wire
R1	51 Ω	Thick Film Resistor	-	-
РСВ	FR-4 (er = 4.3), 30 mil (0.762 mm), 35 μm (1oz)			

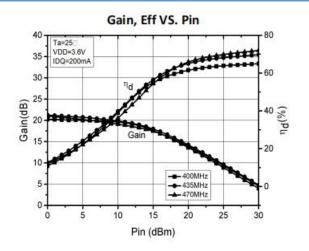


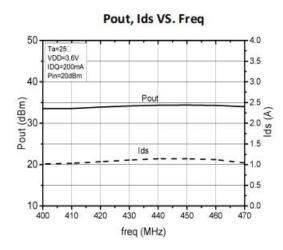
Product datasheet

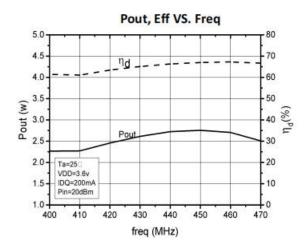
#### **Performance Plots**

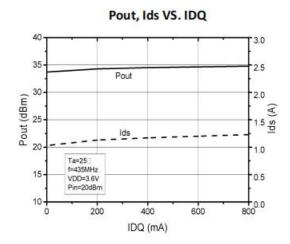
#### 400 - 470 MHz Reference Design, 3.6V@200mA

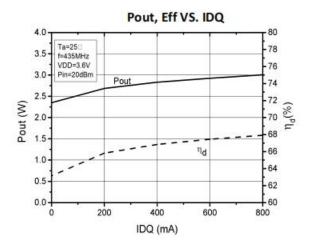








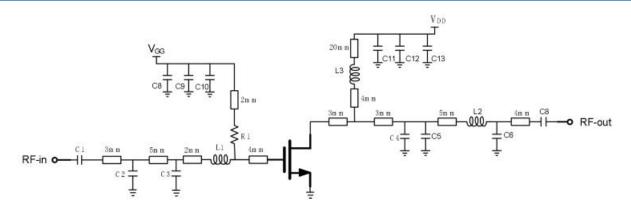




Test conditions unless otherwise noted: 25 °C, VDD = +3.6Vdc, IDQ=200mA, CW test on HOTLO Application Board

Product datasheet

## HTL7G06S009P 400 - 470 MHz Reference Design, 7.2V@200mA



**EVB Layout** 

#### BoM - HTL7G06S009P 400 - 470 MHz Reference Design, 7.2V@200mA

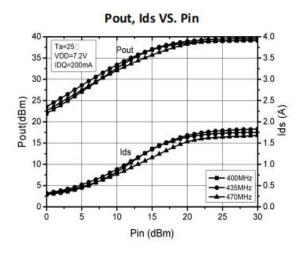
Reference	Value	Description	Manufacturer	P/N	
Q1	-	0.6W, 1.8 - 1000 MHz - LDMOS PA		HTL7G06S009P	
C1,C7, C10, C13	100pF	MLCC	Murata	GRM1885C1H101JA01	
C2, C3	15pF	MLCC	Murata	GRM1885C1H150JA01	
C4, C5	22pF	MLCC	Murata	GRM1885C1H220JA01	
C6	8pF	MLCC	Murata	GRM1885C1H8R0JA01	
C8	4.7uF	MLCC	Murata	GRM32ER61H474KA12L	
C9, C12	1nF	MLCC	Murata	GRM1885C1H102JA01	
C11	10uF	MLCC	Murata	GRM32ER61H105KA12L	
L1		5.6nH/0603	Murata	GRM1885C1H272JA01	
L2	D: 0.4 mi	m, Inside: 1.2 mm, 4 Turns	-	Enameled wire	
L3	D: 0.4 mm, Inside: 1.5 mm, 8 Turns		-	Enameled wire	
R1	51 Ω	Thick Film Resistor	-	-	
РСВ	FR-4 (er = 4.3), 30 mil (0.762 mm), 35 μm (1oz)				

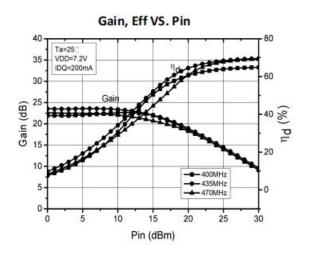


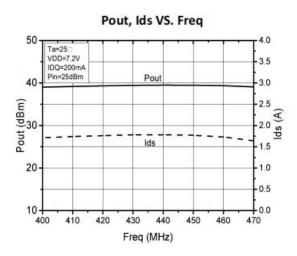
Product datasheet

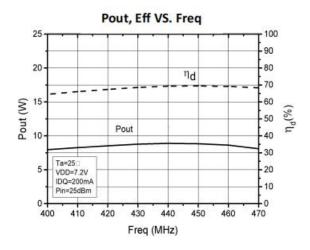
#### **Performance Plots**

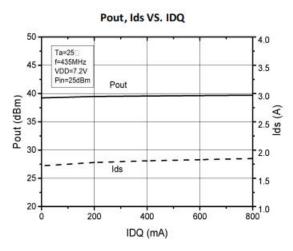
#### 400 - 470 MHz Reference Design, 7.2V@200mA

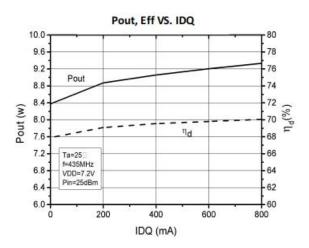








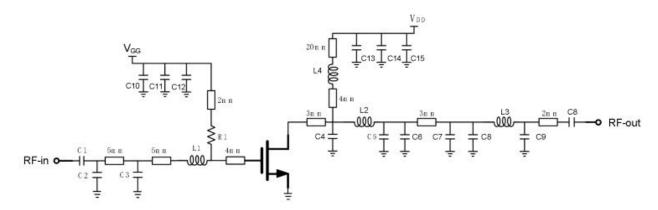




Test conditions unless otherwise noted: 25 °C, VDD = +7.2Vdc, IDQ=200mA, CW test on HOTLO Application Board

Product datasheet

## HTL7G06S009P 136 - 174 MHz Reference Design, 7.2V@200mA



**EVB Layout** 

#### BoM - HTL7G06S009P 136 - 174 MHz Reference Design, 7.2V@200mA

Reference	Value	Description	Manufacturer	P/N
Q1	1	8W, 1.8 - 1000 MHz LDMOS PA	Holto	HTL7G06S009P
C1, C10, C13, C16	100pF	MLCC	Murata	GRM1885C1H101JA01
C2	6pF	MLCC	Murata	GRM1885C1H6R0JA01
C3	27pF	MLCC	Murata	GRM1885C1H270JA01
C4	150pF	MLCC	Murata	GRM1885C1H151JA01
C5,C7	22pF	MLCC	Murata	GRM1885C1H220JA01
C6	18pF	MLCC	Murata	GRM1885C1H180JA01
C8	2pF	MLCC	Murata	GRM1885C1H2R0JA01
С9	10pF	MLCC	Murata	GRM1885C1H100JA01
C12, C15	1nF	MLCC	Murata	GRM1885C1H102JA01
C11	4.7uF	MLCC	Murata	GRM32ER61H474KA12L
C14	10uF	MLCC	Murata	GRM32ER61H105KA12L



## HTL7G06S009P 8W, 1.8 - 1000 MHz LDMOS Amplifier

Product datasheet

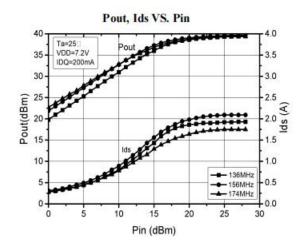
Reference	Value	Description	Manufacturer	P/N
L1	39nH/0603		-	GRM1885C1H393A01
L2, L3	D: 0.4 mı	m, Inside: 1.2 mm, 3 Turns	-	Enameled wire
L4	D: 0.31mm, Inside: 1.5 mm, 9 Turns		-	Enameled wire
R1	50 Ω Thick Film Resistor		-	-
РСВ	FR-4 (er = 4.3), 30 mil (0.762 mm), 35 μm (1oz)			

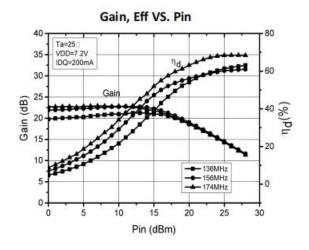


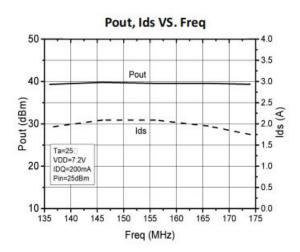
Product datasheet

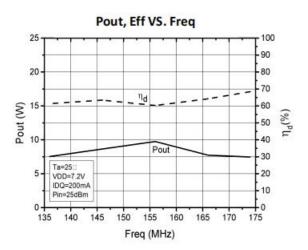
#### **Performance Plots**

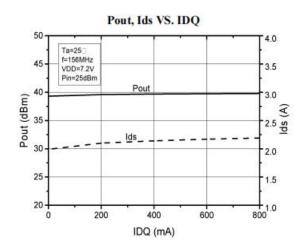
#### 136 - 174 MHz Reference Design, 7.2V@200mA

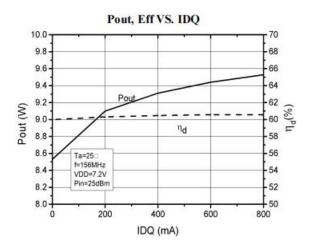












Test conditions unless otherwise noted: 25 °C, VDD = +7.2Vdc, IDQ=200mA, CW test on HOTLO Application Board



Product datasheet

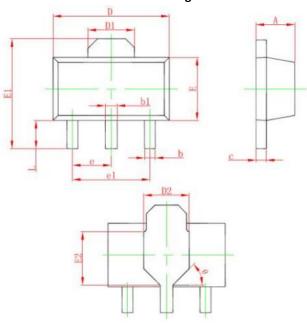
#### **Package Marking and Dimensions**



- Line1 (fixed): fixed code H0609A
- Line2 (unfixed):Date Code + SS(sub lot Number)

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of "Holto Product Printing Specification"

#### Marking



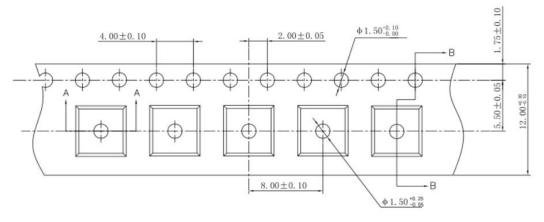
Complete	Dimesions in	n Milimeters	Dimesion	s in Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
D2	1.750 REF.		0.069	REF.
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
E2	1.900	REF.	0.075	REF.
е	1.500 TYP.		0.060 TYP.	
e1	3.000	TYP.	0.118 TYP.	
L	0.900	1.200	0.035	0.047
θ	4	5°	45°	

**Package Dimensions** 

Product datasheet

## **Tape and Reel Information**

Package Type	Reel Size(inch)	Qty/Reel(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)
SOT89	7inches	1000	10000	40000



**Tape & Reel Packaging Descriptions** 

#### **Handling Precautions**

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114
ESD – Human Body Model (MM)	Class A	EIA/JESD22-A115
ESD – Charged Device Model (CDM)	Class III	JESD22-C101



#### **RoHS Compliance**

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

#### **Datasheet Status**

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification

# **HOLTO**

## HTL7G06S009P 8W, 1.8 - 1000 MHz LDMOS Amplifier

Product datasheet

#### **Abbreviations**

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform

## **Revision history**

Document ID	Datasheet Status	Release Date	Revision Version
Rev 3.0	Product	July 2021	The silkscreen was updated to
			"H0609A".
			The company name was updated to
			"Suzhou Holto Electronics Technology
			Co. Ltd."
Rev 3.1 Pr	Draduct	March 2023	New format based on English version
	Product		datasheet
Rev 3.2	Product	March 2024	Version released after re review

## HTL7G06S009P



## 8W, 1.8 - 1000 MHz LDMOS Amplifier

#### **Contact Information**

Product datasheet

For the latest specifications, additional product information, worldwide sales and distribution locations and information about HOTLO:

• Web: www.andesource.com

• Email: andehk@andesource.com

For technical questions and application information:

Email: andetech@andesource.com

#### **Important Notice**

Information in this document is believed to be accurate and reliable. However, HOTLO does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

"Typical" parameters are the average values expected by HOTLO in large quantities and are provided for information purposes only. All information and specifications contained herein are subject to change without notice and customers should obtain and verify the latest relevant information before placing orders for HOTLO products.

The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information.

Applications that are described herein for any of these products are for illustrative purposes only. HOTLO makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using HOTLO products, and HOTLO accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the HOTLO product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third-party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

HOTLO products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety- critical systems or equipment, nor in applications where failure or malfunction of a HOTLO product can reasonably be expected to result in personal injury, death or severe property or environmental damage. This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.